

## **IXFH40N85X Datasheet**



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DiGi Electronics Part Number IXFH40N85X-DG

Manufacturer IXYS

Manufacturer Product Number IXFH40N85X

Description MOSFET N-CH 850V 40A TO247

Detailed Description N-Channel 850 V 40A (Tc) 860W (Tc) Through Hole

TO-247



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## **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
IXFH40N85X	IXYS
Series:	Product Status:
HiPerFET™, Ultra X	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
850 V	40A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
10V	145mOhm @ 500mA, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
5.5V @ 4mA	98 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±30V	3700 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	860W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Supplier Device Package:	Package / Case:
TO-247	TO-247-3
Base Product Number:	
IXFH40	

## **Environmental & Export classification**

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	

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## **OUR CERTIFICATE**

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